

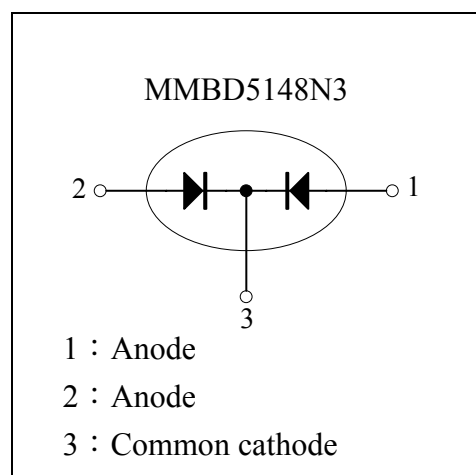
High –speed double diode

MMBD5148N3

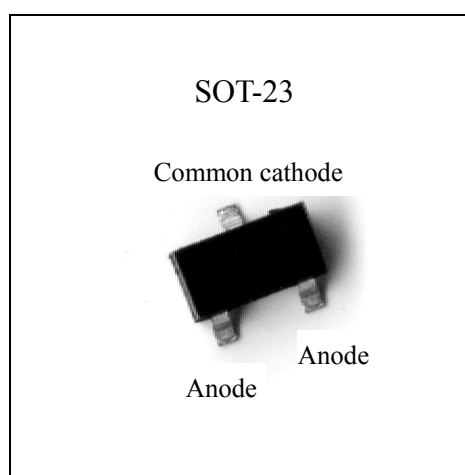
Description

The MMBD5148N3 consists of two high-speed switching diodes with common cathodes, fabricated in planar technology, and encapsulated in the small SOT-23 plastic SMD package.

Equivalent Circuit



Outline



Features

- Small plastic SMD package
- High switching speed: max. 4ns
- Continuous reverse voltage: max. 100V
- Repetitive peak reverse voltage: max. 100V
- Repetitive peak forward current: max. 450mA.

Applications

- High-speed switching in thick and thin-film circuits.

**Absolute Maximum Ratings @T_A=25°C**

Parameters	Symbol	Min	Max	Unit
Repetitive peak reverse voltage	V _{RRM}	-	100	V
Continuous reverse voltage	V _R	-	100	V
Continuous forward current(single diode loaded)	I _F	-	215	mA
Continuous forward current(double diode loaded)		-	125	
Repetitive peak forward current	I _{FRM}		450	mA
Non-repetitive peak forward current @square wave, T _j =125°C prior to surge	I _{FSM}	t=1μs	4	A
		t=1ms	1	A
		t=1s	0.5	A
Total power dissipation(Note 1)	P _{tot}		250	mW
Junction Temperature	T _j	-	150	°C
Storage Temperature	T _{stg}	-65	+150	°C

Note 1: Device mounted on an FR-4 PCB.

Electrical Characteristics @ T_j=25°C unless otherwise specified

Parameters	Symbol	Conditions	Min	Typ.	Max	Unit
Forward voltage	V _F	I _F =1mA	-	-	715	mV
		I _F =10mA			855	mV
		I _F =50mA			1	V
		I _F =150mA			1.25	V
Reverse current	I _R	V _R =100V	-	-	30	nA
		V _R =25V, T _j =150°C			60	μA
		V _R =75V, T _j =150°C			100	μA
Diode capacitance	C _d	V _R =0V, f=1MHz	-	-	1.5	pF
Reverse recovery time	t _{rr}	when switched from I _F =10mA to I _R =10mA, R _L =100Ω, measured at I _R =1mA	-	-	4	ns
Forward recovery voltage	V _{fr}	when switched from I _F =10mA t _r =20ns	-	-	1.75	V

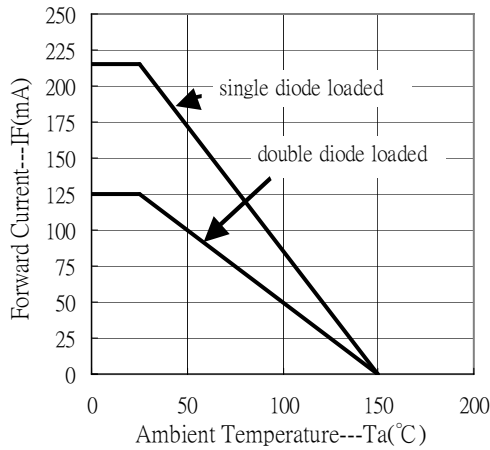
Thermal Characteristics

Symbol	Parameter	Conditions	Value	Unit
R _{th,j-tp}	thermal resistance from junction to tie-point		360	°C/W
R _{th, j-a}	thermal resistance from junction to ambient	Note 1	500	°C/W

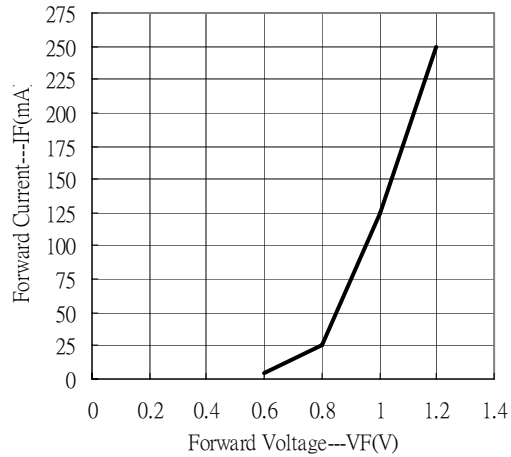
Note 1: Device mounted on an FR-4 PCB.

Characteristic Curves

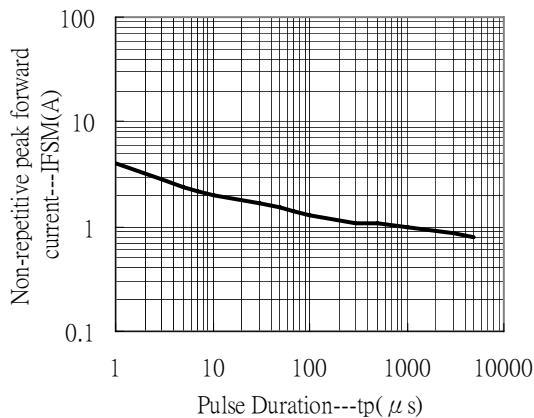
Forward Current vs Ambient Temperature



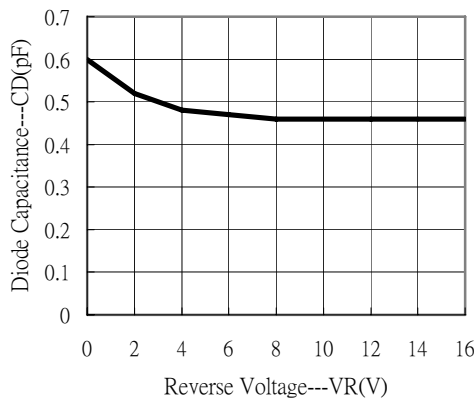
Forward Current vs Forward Voltage



Non-repetitive peak forward current vs pulse duration



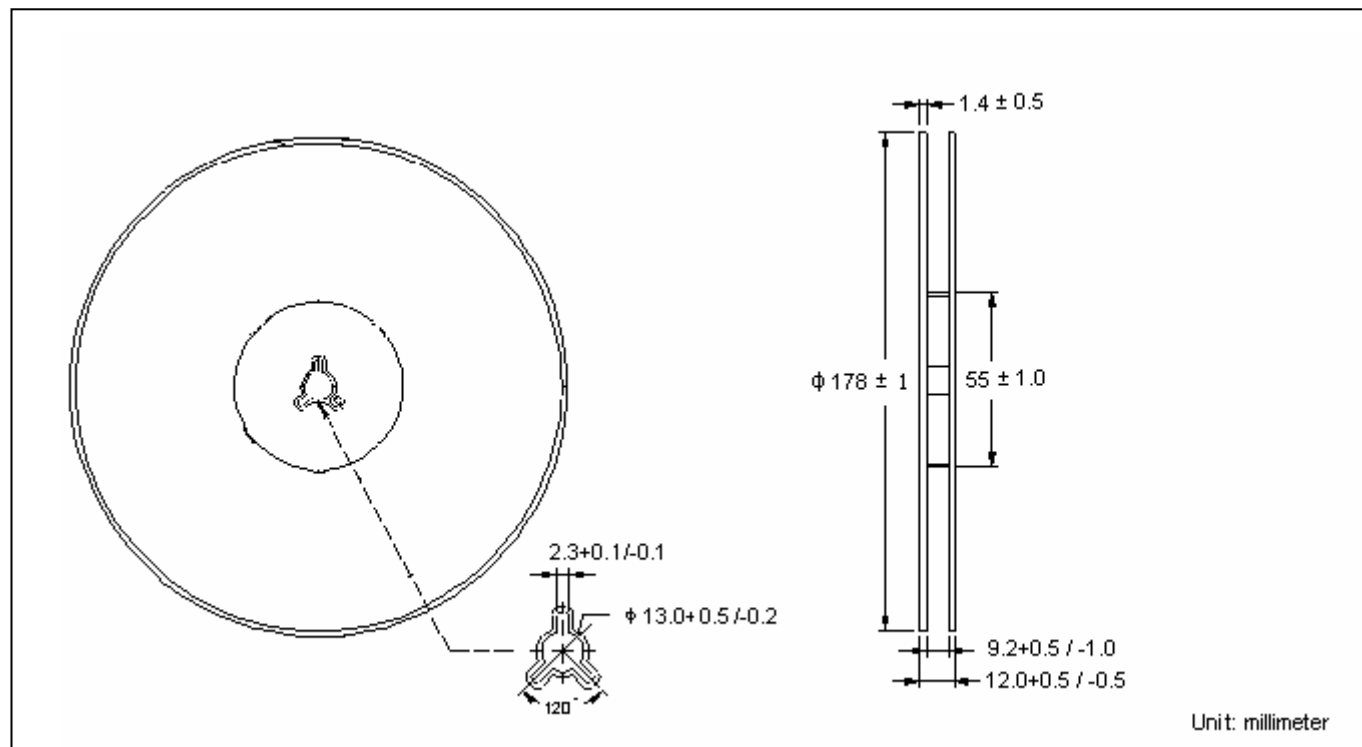
Diode Capacitance vs Reverse Voltage



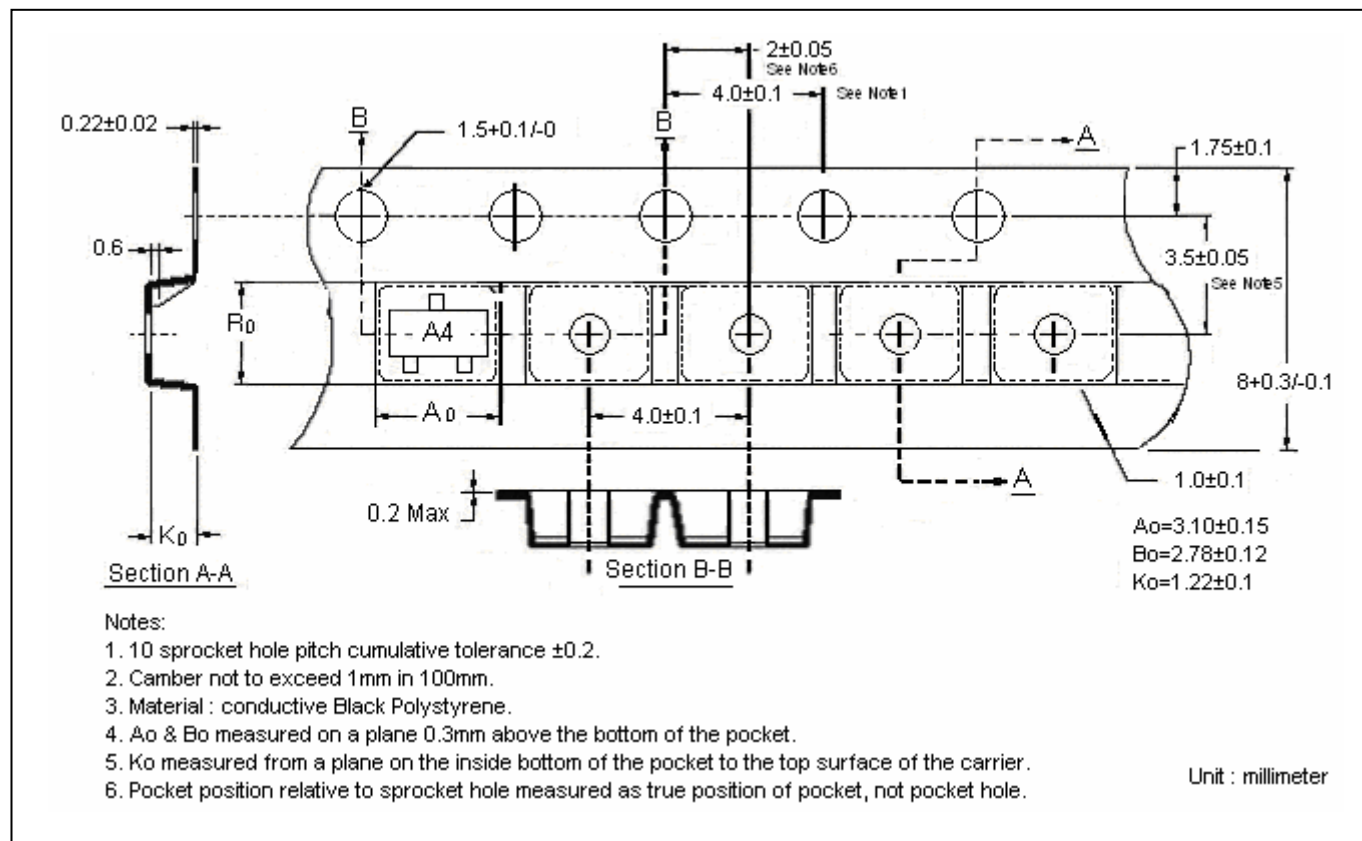
Ordering Information

Device	Package	Shipping	Marking
MMBD5148N3	SOT-23 (Pb-free)	3000 pcs / Tape & Reel	A4

Reel Dimension



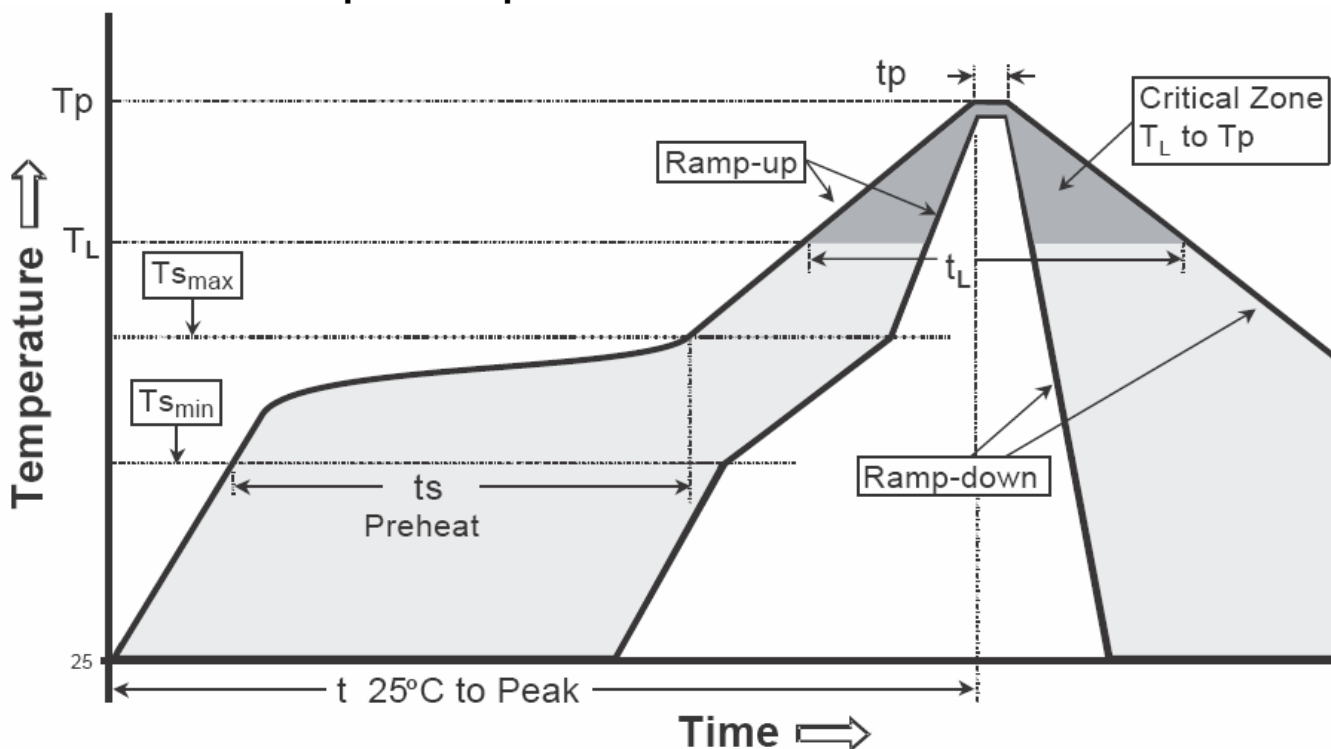
Carrier Tape Dimension



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

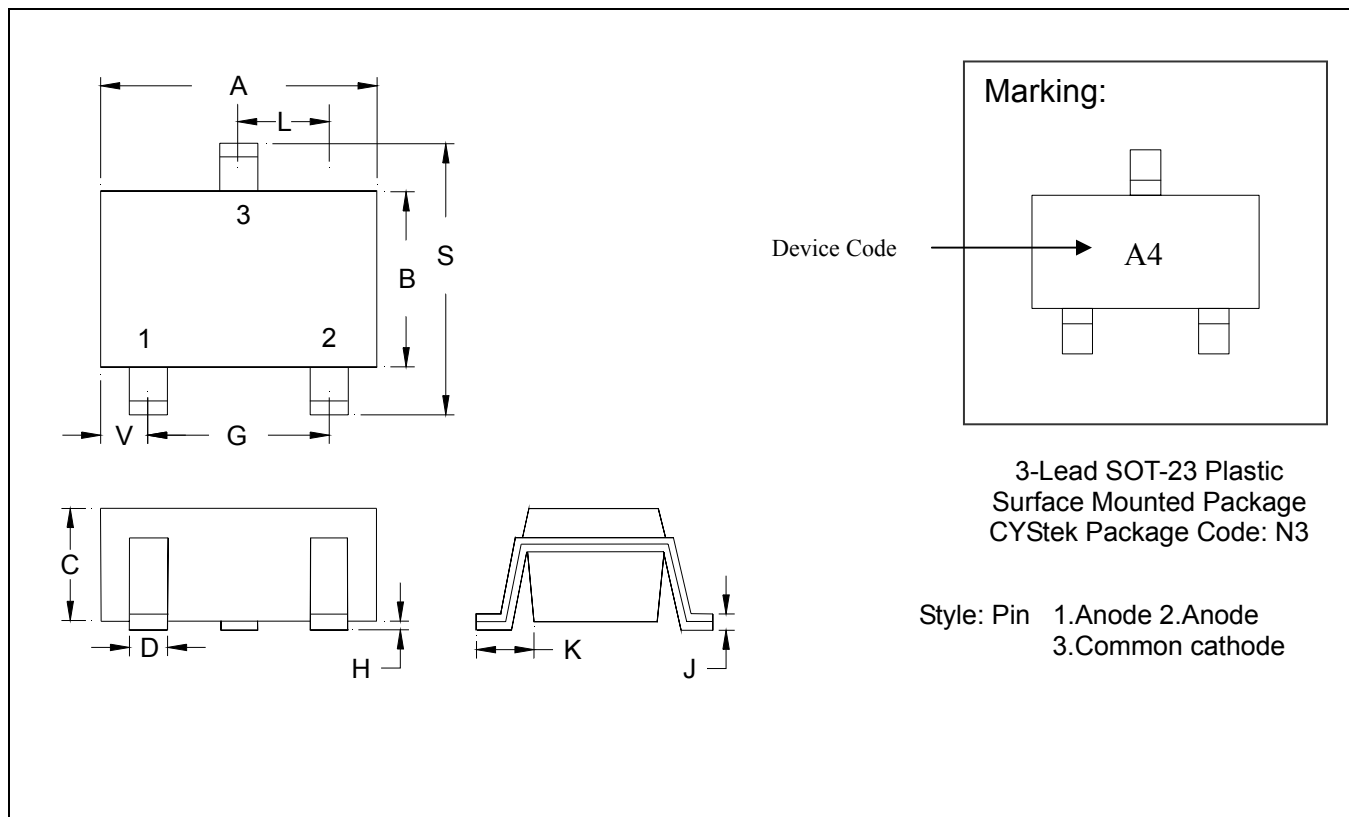
Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(Ts min)	100°C	150°C
-Temperature Max(Ts max)	150°C	200°C
-Time(ts min to ts max)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (Tl)	183°C	217°C
- Time (tL)	60-150 seconds	60-150 seconds
Peak Temperature(Tp)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

SOT-23 Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1102	0.1204	2.80	3.04	J	0.0034	0.0070	0.085	0.177
B	0.0472	0.0630	1.20	1.60	K	0.0128	0.0266	0.32	0.67
C	0.0335	0.0512	0.89	1.30	L	0.0335	0.0453	0.85	1.15
D	0.0118	0.0197	0.30	0.50	S	0.0830	0.1083	2.10	2.75
G	0.0669	0.0910	1.70	2.30	V	0.0098	0.0256	0.25	0.65
H	0.0005	0.0040	0.013	0.10					

Notes: 1. Controlling dimension: millimeters.

2. Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3. If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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